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3.2 x 2.5 x 1.0mm 6 pad SMD CMOS

- Frequency range 1.25MHz to 50.0MHz
- CMOS/TTL Output
- Supply Voltage 1.8V, 2.5V, or 3.3V or 5.0VDC
- Integrated Phase Jitter 200fs typical, 1ps max.
- Fundamental mode crystals for best phase noise performance







SUPPLY VOLTAGE DEPENDENT SPECIFICATION

Model:	'G' Series					
Input Voltage:	Vdd = +1.8VDC±5%	$Vdd = +2.5VDC \pm 5\%$	$Vdd = +3.3VDC \pm 5\%$	$Vdd = +5.0VDC \pm 10\%$		
Frequency Range*:	16.0MHz ~ 50.0MHz	1.25MHz ~ 50.0MHz	1.25MHz ~ 50.0MHz	1.25MHz ~ 50.0MHz		
Output Wave Form:	CMOS/TTL					
Initial Freq. Accuracy	Tune with Vc = 0.9V±0.15V	Tune with Vc = 1.25V±0.2V	Tune with Vc = 1.65V±0.2V	Tune with Vc = 2.5V±0.2V		
Output Logic High '1'	1.62V minimum	2.25V minimum	2.97V minimum	4.5V minimum		
Output Logic Low '0'	0.183V maximum	0.25V maximum	0.33V maximum	0.5V maximum		
Frequency Deviation Range:	Standard ±80ppm min.	Standard ±80ppm min.	Standard ±80ppm min.	Standard ±80ppm min. ±200ppm available		
Control Voltage Centre:	0.9VDC	1.25VDC	1.65 VDC	2.5 VDC		
Control Voltage Range:	0.0V to 1.8V	0.25V to 2.25V	0.3V to 3.0V	0.5V to 1.5V		

GENERAL SPECIFICATION

Frequency Stability: See table

Output Load

TTL: 2 TTL gates CMOS: 15pF

Rise/Fall Times

TTL: 6ns max., 4ns typical

Measured between 0.4V to 2.4V

CMOS: 6ns max., 4ns typical

Measured between 20% to 80% of

wave form, (CL = 15pF)

Duty Cycle: $50\%\pm10\%$ standard, $50\%\pm5\%$ is

available, add 'S' to part number 200fs typ. 1ps max(12kHz to 20MHz)

Integrated Phase Jitter: 200fs typ. 1ps max(12kHz to Start-up Time: 10ms max., 5ms typical Current Consumption: 10~45mA, freq. dependant

e.g. 27MHz: 10mA @ 3.3V

27MHz: 20mA @5.0V

6% typical, 10% max.

Modulation Bandwidth: 10kHz min. Measured at -3dB with

V control at 1.65V or 2.5V

Input Impedance: 5MΩ typical

Slope Polarity: Monotonic and positive (An

increase of control voltage increases output frequency.)

Ageing: ±3ppm per year max.

Tri-state

Linearity:

Enable high: No connection of VDD-0.5V min. is

applied to Tri-state pin to enable.

Disable: Ground +0.5V max. disables

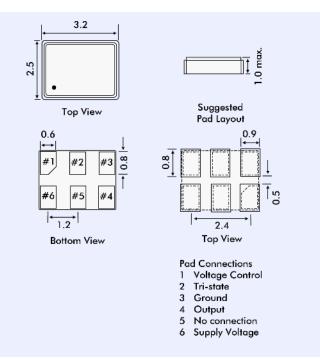
output. (High impedance)

PHASE NOISE

Characteristics typical of 27MHz, +3.3V supply.

Offset	10Hz	100Hz	1 kHz	10kHz	100kHz	1MHz
dBc/Hz	-40	-104	-132	-147	-152	-150

OUTLINE AND DIMENSIONS



FREQUENCY STABILITY OVER TEMPERATURE*

Frequency Stability over Operating Temp. Range**	±25ppm	±50ppm	±100ppm
Commercial -10° to +70°C	Α	В	С
Industrial -40 to +85°C	D	Е	F

^{*} See ordering information

Example: $C20' = \pm 20$ ppm over -10 to ± 70 °C

Issue 2

^{**} If non-standard temperature stability is required enter the required stability (in ppm) after either 'C' (-10° to +70°) or 'I' (-40° to +85°C)

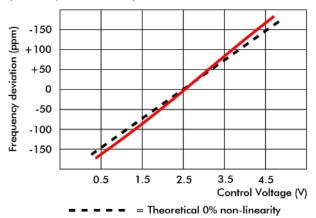


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TRANSFER FUNCTION

Typical response of 3G326-C-150N-27.000 (at 25°C, positive transfer)



PART NUMBER SCHEDULE

